# Hex 3-State Noninverting Buffer with Common Enables

## High-Performance Silicon-Gate CMOS

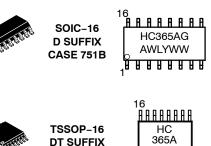
The MC74HC365A is identical in pinout to the LS365. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

This device is a high-speed hex buffer with 3-state outputs and two common active-low Output Enables. When either of the enables is high, the buffer outputs are placed into high-impedance states. The HC365A has noninverting outputs.

### Features

- Output Drive Capability: 15 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0 µA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the Requirements Defined by JEDEC Standard No. 7A
- Chip Complexity: 90 FETs or 22.5 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant





AI V/A/

1	CASE 948F	
		1
А	= Assembly Location	n
WL, L	= Wafer Lot	
YY, Y	= Year	
WW, W	= Work Week	
G or ∎	= Pb-Free Package	
(Note: Mi	crodot may be in eithe	er location)

### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 2 of this data sheet.

1

	1●	16	l v <sub>cc</sub>
A0 [	2	15	OUTPUT ENABLE 2
Y0 [	3	14	] A5
A1 [	4	13	] Y5
Y1 [	5	12	] A4
A2 [	6	11	] Y4
Y2 [	7	10	] A3
GND [	8	9	] Y3

Figure 1. Pin Assignment

#### FUNCTION TABLE

	Output		
Enable 1	Enable 2	А	Y
L	L	L	L
L	L	н	н
н	X	X	Z
Х	н	Х	Z
X = don't	care		

Z = high impedance

**ORDERING INFORMATION** 

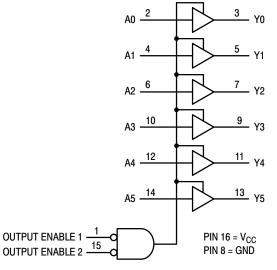


Figure 2. Logic Diagram

Device	Package	Shipping <sup>†</sup>
MC74HC365ADG	SOIC-16 (Pb-Free)	48 Units / Rail
MC74HC365ADR2G	SOIC-16 (Pb-Free)	2500 Units / Tape & Reel
MC74HC365ADTR2G	TSSOP-16 (Pb-Free)	2500 Units / Tape & Reel
NLV74HC365ADTR2G*	TSSOP-16 (Pb-Free)	2500 Units / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

## MAXIMUM RATINGS\*

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)	– 0.5 to + 7.0	V
V <sub>in</sub>	DC Input Voltage (Referenced to GND)	$-0.5$ to $V_{CC}$ + 0.5	V
V <sub>out</sub>	DC Output Voltage (Referenced to GND)	$-0.5$ to $V_{CC}$ + 0.5	V
l <sub>in</sub>	DC Input Current, per Pin	± 20	mA
l <sub>out</sub>	DC Output Current, per Pin	± 25	mA
I <sub>CC</sub>	DC Supply Current, V <sub>CC</sub> and GND Pins	± 50	mA
P <sub>D</sub>	Power Dissipation in Still Air, SOIC Package† TSSOP Package†	500 450	mW
T <sub>stg</sub>	Storage Temperature	– 65 to + 150	°C
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds SOIC or TSSOP Package	260	°C

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high-impedance circuit. For proper operation,  $V_{in}$  and  $V_{out}$  should be constrained to the range GND  $\leq (V_{in} \text{ or } V_{out}) \leq V_{CC}$ .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or  $V_{CC}$ ). Unused outputs must be left open.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

†Derating — SOIC Package: – 7 mW/°C from 65° to 125°C

TSSOP Package: - 6.1 mW/°C from 65° to 125°C

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Max	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)			6.0	V
V <sub>in</sub> , V <sub>out</sub>	DC Input Voltage, Output Voltage (Referenced to GND)		0	V <sub>CC</sub>	V
T <sub>A</sub>	Operating Temperature, All Package Types		- 55	+ 125	°C
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Figure 1)	$V_{CC} = 2.0 V \\ V_{CC} = 3.0 V \\ V_{CC} = 4.5 V \\ V_{CC} = 6.0 V$	0 0 0	1000 600 500 400	ns

#### DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

				Gu	aranteed Li	mit	
Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
VIH	Minimum High–Level Input Voltage	$V_{out} = V_{CC} - 0.1 V$ $ I_{out}  \le 20 \mu A$	2.0 3.0 4.5 6.0	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	1.5 2.1 3.15 4.2	V
VIL	Maximum Low–Level Input Voltage	$V_{out} = 0.1 V$ $ I_{out}  \le 20 \mu A$	2.0 3.0 4.5 6.0	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	0.50 0.90 1.35 1.80	V
V <sub>OH</sub>	Minimum High–Level Output Voltage	$V_{in} = V_{IH}$ $ I_{out}  \le 20 \ \mu A$	2.0 4.5 6.0	1.9 4.4 5.9	1.9 4.4 5.9	1.9 4.4 5.9	V
		$ \begin{array}{ll} V_{in} = V_{IH} &  \left  I_{out} \right  \leq 3.6 \text{ mA} \\ \left  I_{out} \right  \leq 6.0 \text{ mA} \\ \left  I_{out} \right  \leq 7.8 \text{ mA} \end{array} $	4.5	2.48 3.98 5.48	2.34 3.84 5.34	2.20 3.70 5.20	
V <sub>OL</sub>	Maximum Low–Level Output Voltage	$V_{in} = V_{IL}$ $ I_{out}  \le 20 \ \mu A$	2.0 4.5 6.0	0.1 0.1 0.1	0.1 0.1 0.1	0.1 0.1 0.1	V
		$\begin{array}{ll} V_{in} = V_{IL} &  \left I_{out}\right  \leq 3.6 \text{ mA} \\ \left I_{out}\right  \leq 6.0 \text{ mA} \\ \left I_{out}\right  \leq 7.8 \text{ mA} \end{array}$	4.5	0.26 0.26 0.26	0.33 0.33 0.33	0.40 0.40 0.40	

### DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

				Gu	Guaranteed Limit		
Symbol	Parameter	Test Conditions	V <sub>CC</sub> V	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
l <sub>in</sub>	Maximum Input Leakage Current	$V_{in} = V_{CC}$ or GND	6.0	± 0.1	±1.0	± 1.0	μA
l <sub>oz</sub>	Maximum Three-State Leakage Current	Output in High-Impedance State $V_{in} = V_{IL} \text{ or } V_{IH}$ $V_{out} = V_{CC} \text{ or GND}$	6.0	± 0.5	±5.0	± 10	μA
Icc	Maximum Quiescent Supply Current (per Package)	$V_{in} = V_{CC}$ or GND $I_{out} = 0 \ \mu A$	6.0	4	40	160	μΑ

## AC ELECTRICAL CHARACTERISTICS ( $C_L$ = 50 pF, Input $t_r$ = $t_f$ = 6 ns)

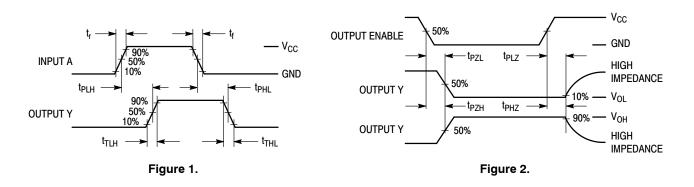
			Gu	aranteed Li	mit	
Symbol	Parameter	V <sub>CC</sub> V	– 55 to 25°C	≤ 85°C	≤ 125°C	Unit
t <sub>PLH</sub> , t <sub>PHL</sub>	Maximum Propagation Delay, Input A to Output Y (Figures 1 and 3)	2.0 3.0 4.5 6.0	120 60 24 20	150 75 30 26	180 90 36 31	ns
t <sub>PLZ</sub> , t <sub>PHZ</sub>	Maximum Propagation Delay, Output Enable to Output Y (Figures 2 and 4)	2.0 3.0 4.5 6.0	220 110 44 37	275 140 55 47	330 170 66 56	ns
t <sub>PZL</sub> , t <sub>PZH</sub>	Maximum Propagation Delay, Output Enable to Output Y (Figures 2 and 4)	2.0 3.0 4.5 6.0	220 110 44 37	275 140 55 47	330 170 66 56	ns
t <sub>TLH</sub> , t <sub>THL</sub>	Maximum Output Transition Time, Any Output (Figures 1 and 3)	2.0 3.0 4.5 6.0	60 22 12 10	75 28 15 13	90 34 18 15	ns
C <sub>in</sub>	Maximum Input Capacitance	_	10	10	10	pF
C <sub>out</sub>	Maximum Three-State Output Capacitance (Output in High-Impedance State)	—	15	15	15	pF
			Typical	@ 25°C, V <sub>C</sub>	<sub>C</sub> = 5.0 V	

C<sub>PD</sub> Power Dissipation Capacitance (Per Buffer)\* 60

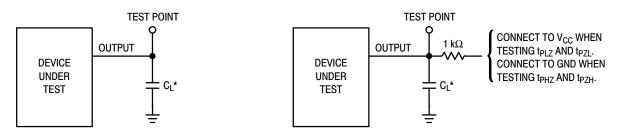
\*Used to determine the no-load dynamic power consumption:  $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$ .

## SWITCHING WAVEFORMS

pF



## **TEST CIRCUITS**



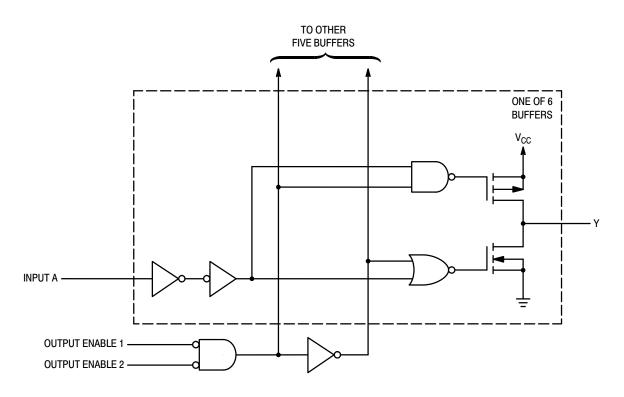
\*Includes all probe and jig capacitance

Figure 3.

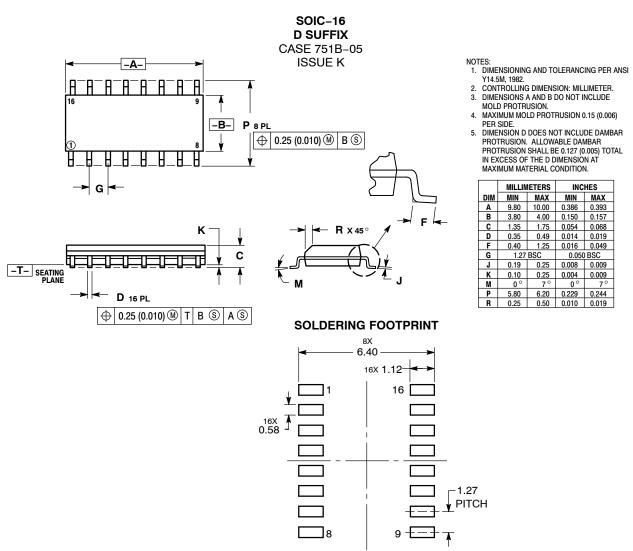
\*Includes all probe and jig capacitance

Figure 4.

## LOGIC DETAIL



### PACKAGE DIMENSIONS



DIMENSIONS: MILLIMETERS

### PACKAGE DIMENSIONS

INCHES

0.026 BSC

0.252 BSC

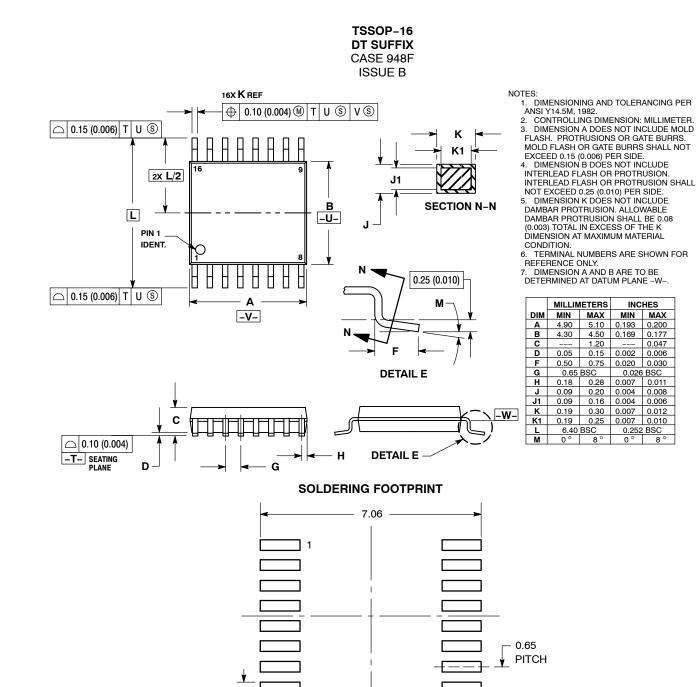
0

MIN MAX

0.047

0.008

8



1 16X

0.36

16X

1.26

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